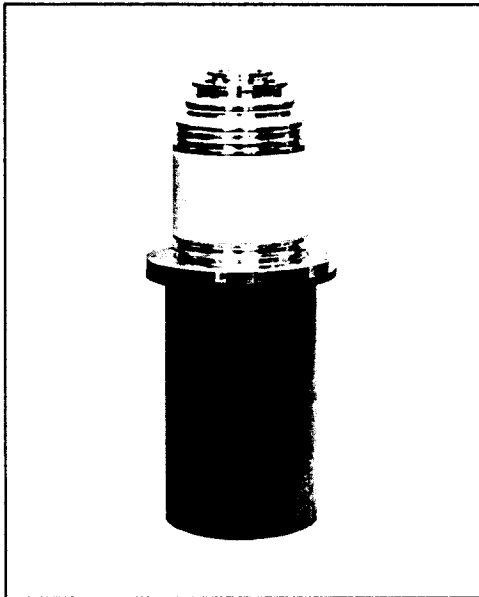


The Machlett Laboratories, Inc.  
 1063 Hope Street • Stamford, Conn. 06907  
 Tel. 203-348-7511 • TWX 710-474-1744



ISSUED 4-71

ML-8785

ML-8786



**General Purpose Tetrodes**  
 350 kW CW  
 12.0 Mw Pulsed

**DESCRIPTION**

The ML-8785 and ML-8786 are general purpose tetrodes capable of 350 kW continuous output as a Class C amplifier or oscillator. The ML-8785 is provided with a vapor-cooled anode; the ML-8786 is water-cooled.

The anodes of both tubes are designed to dissipate 175 kW during continuous operation and substantially higher power during momentary overloads or intermittent operation. Co-

axial grid and cathode mounting structures provide low-inductance, high-dissipation rf terminals. The cathode consists of sturdy thoriated-tungsten filaments. Low-loss alumina ceramics are used for all insulation members.

Maximum ratings apply at frequencies up to 30 MHz. Useful power output can be obtained at higher frequencies with an appropriate reduction in ratings.

**GENERAL CHARACTERISTICS**

**Electrical**

Filament Voltage .....	15.0	V†
Filament Current .....	400	A
Filament Starting Current, maximum .....	1000	A
Filament Cold Resistance .....	.0043	ohm
Amplification Factor, Control Grid to Screen Grid, approx. ....	5	
Direct Interelectrode Capacitances		
Control Grid to Plate .....	6.5	pf
Control Grid to Cathode .....	240	pf
Control Grid to Screen Grid .....	390	pf
Plate to Cathode .....	2	pf
Screen Grid to Plate .....	130	pf
Screen Grid to Cathode .....	40	pf
Strapped Resonant Frequencies, approx.		
Screen Grid to Plate .....	125	MHz
Screen Grid to Control Grid .....	92	MHz
Control Grid to Cathode .....	96	MHz

†For peak cathode currents in excess of 375 A, filament voltage must be 15.5 V.

\*The given water cooling characteristics apply for typical RF and AF operation as given in this data sheet. In specialized applications involving relatively high plate voltages and low plate currents, electron beaming may occur requiring increased water flow rates for cooling. Consult the Machlett Laboratories Engineering Department regarding further cooling information for special applications.

\*\*Air flow should be distributed to maintain a uniform temperature, not greater than 200°C, on the ceramic insulators and the circumference of the seals. At frequencies above 15 MHz, special attention should be given to cooling the seals. At frequencies above 30 MHz, additional air flow may be required to maintain seal temperature below the specified maximum.

**Mechanical**

Mounting Position .....	Anode down
Type of Anode Cooling, ML-8785 .....	Vaporization of water
Type of Anode Cooling, ML-8786 .....	Water
Water flow on anode for 175 kW dissipation, min. ....	46 gpm*
Maximum outgoing water temperature .....	70 °C
Maximum water pressure .....	80 psi
Maximum Envelope Temperature .....	200 °C
Air Flow on Insulators and Seals, approx. ....	500 cfm**
Net Weight, approximate	
ML-8785 .....	130 lb
ML-8786 .....	115 lb

**WARNING:** This electron tube when operated at peak voltages in excess of 15 kv may give off x-rays, which can be harmful unless adequately shielded by the enclosure within which the tube is used. Instructions for protective installation are given in National Bureau of Standards Handbook 93, "Safety Standards for Non-Medical X-Ray and Sealed Gamma Ray Sources".

**ACCESSORIES**

Item	Part No.
Small Filament Connector .....	P-510187
Large Filament Connector .....	P-510188
Control-Grid Connector .....	P-510206
Screen-Grid Connector .....	F-27220
Vapor-Cooling Jacket, Vapor-Up System (ML-8785) .....	P-27899
Vapor-Cooling Jacket, Vapor-Down System (ML-8785) .....	P-28903
O Ring (ML-8785) .....	P-25946
One-Tube Dolly .....	S-16097
Two-Tube Dolly .....	S-16096

NOTE: Additional information on accessories will be supplied on request.

**MAXIMUM RATINGS AND TYPICAL OPERATING CONDITIONS**

(Continuous Commercial Service)

VALUES APPLY TO BOTH TYPES UNLESS OTHERWISE SPECIFIED

**RF Power Amplifier or Oscillator  
Class C Telephony**

Key-down condition per tube without amplitude modulation.§

Maximum Ratings, Absolute Values

DC Plate Voltage .....	18	kV
DC Screen-Grid Voltage .....	2500	V
DC Control-Grid Voltage .....	-1200	V
Screen-Grid Dissipation .....	3000	W
Control-Grid Dissipation .....	1000	W
Plate Dissipation .....	175	kW

Typical Operation

DC Plate Voltage .....	16	18	kV
Peak RF Plate Voltage .....	13.5	15.5	kv
DC Screen-Grid Voltage .....	1500	1500	V
DC Control-Grid Voltage .....	-900	-1000	V
Peak RF Control-Grid Voltage .....	1170	1300	v
DC Plate Current .....	25	25	A
DC Screen-Grid Current .....	2.0	2.0	A
DC Control-Grid Current .....	.38	.42	A
Peak Fundamental RF Plate Current .....	43	45	a
Load Impedance .....	314	345	ohms
Driving Power, approximate .....	420	510	W
Plate Dissipation .....	110	100	kW
Plate Output Power .....	290	350	kW

**Plate-Modulated RF Power Amplifier  
Class C Telephony**

Carrier condition except where noted for use with a maximum modulation factor of 1.0

Maximum Ratings, Absolute Values

DC Plate Voltage .....	13	kV
DC Screen-Grid Voltage .....	2000	V
DC Control-Grid Voltage .....	-1200	V
Screen-Grid Dissipation .....	3000	W
Control-Grid Dissipation .....	1000	W
Plate Dissipation .....	117	kW

Typical Operation

DC Plate Voltage .....	11	13	kV
Peak RF Plate Voltage .....	9	11	kv
DC Screen-Grid Voltage .....	750	750	V
DC Control-Grid Voltage .....	-600	-600	V

Peak AF Screen-Grid Voltage for 100%

Modulation .....	750	750	v
Peak RF Control-Grid Voltage .....	910	910	v
DC Plate Current .....	20.8	19.0	A
DC Screen-Grid Current .....	2.7	2.7	A
DC Control-Grid Current .....	1.7	1.7	A
Peak Fundamental RF Plate Current .....	34	34	a
Load Impedance .....	265	323	ohms
Driving Power, approximate .....	1430	1430	W
Plate Output Power .....	153	187	kW
Plate Dissipation .....	55	60	kW

**AF Power Amplifier or Modulator  
Class AB**

Maximum Ratings, Absolute Values (per tube)

DC Plate Voltage .....	18	kV
DC Screen-Grid Voltage .....	2500	V
DC Control-Grid Voltage .....	-1200	V
Screen-Grid Dissipation† .....	3000	W
Control-Grid Dissipation‡ .....	1000	W
Plate Dissipation‡ .....	175	kW

Typical Operation (Values are for two tubes, sinusoidal wave)

DC Plate Voltage .....	16	16	kV
DC Screen-Grid Voltage .....	1500	1500	V
DC Control-Grid Voltage .....	-400	-400	V
Peak AF Driving Voltage, per tube .....	400	575	v
Zero-Signal DC Plate Current .....	5	6	A
Maximum-Signal DC Plate Current .....	32	62	A
Maximum-Signal DC Screen-Grid Current .....	2.0	4.2	A
Maximum-Signal DC Control-Grid Current .....	0	.31	A
Driving Power .....	0	167	W
Load Resistance, plate-to-plate .....	1080	630	ohms
Plate Dissipation, per tube .....	92	170	kW
Maximum-Signal Plate Output Power .....	338	658	kW

**Linear RF Power Amplifier  
Class AB Single-Sideband,  
Suppressed-Carrier Service**

Maximum Ratings

DC Plate Voltage .....	18	kV
DC Screen-Grid Voltage .....	2750	V
DC Control-Grid Voltage .....	-1200	V
Screen-Grid Dissipation .....	3000	W
Control-Grid Dissipation .....	1000	W
Plate Dissipation .....	175	kW

Typical Operation for Single-Tone Modulation

DC Plate Voltage .....	18	18	18	kV
DC Screen-Grid Voltage .....	820	1500	2000	V
DC Control-Grid Voltage .....	-260	-400	-550	V
Maximum-Signal DC Plate Current .....	9.5	14.4	22	A
Zero Signal DC Plate Current .....	2	5	7	A
Maximum-Signal DC Screen-Grid Current .....	.5	1.0	1.5	A
Peak RF Control-Grid Voltage .....	260	400	550	v
Driving Power .....	0	0	0	W
Peak Fundamental RF Plate Current .....	15.0	22.5	34.5	a
Load Impedance .....	1070	710	435	ohms
Plate Dissipation .....	51	80	136	kW
Plate Output Power .....	120	180	260	kW

### Pulse Modulator or Pulse Amplifier

#### Maximum Ratings, Absolute Values\*

DC Plate Voltage .....	40	kV
Peak Plate Voltage .....	50	kv
DC Screen-Grid Voltage .....	2750	V
DC Control-Grid Voltage .....	-3000	V
Peak Negative Control-Grid Voltage .....	-5000	v
Pulse Cathode Current		
With 15.0 V filament voltage .....	375	a
With 15.5 V filament voltage .....	500	a
Control-Grid Dissipation .....	1000	W
Screen-Grid Dissipation .....	3000	W
Plate Dissipation .....	175	kW
Pulse Duration .....	1000	$\mu$ s**
Duty Factor .....	.01	**

#### Typical Operation

DC Plate Voltage .....	40	kV
DC Screen-Grid Voltage .....	2750	V
DC Control-Grid Voltage .....	-2000	V
Pulse Positive Control-Grid Voltage .....	750	V
Pulse Plate Current .....	300	a
Pulse Screen-Grid Current .....	45	a
Pulse Control-Grid Current .....	17	a
Pulse Driving Power .....	47	kw
Pulse Output Power .....	10.5	Mw
Pulse Output Voltage .....	35	kv
Duty Factor .....	.01	

### Plate-Pulsed RF Power Amplifier or Oscillator Class C

#### Maximum Ratings, Absolute Values\*

Peak Plate Pulse Supply Voltage .....	30	kv
Peak Screen-Grid Pulse Supply Voltage .....	2750	v
DC Control-Grid Voltage .....	-3000	V
Peak Cathode Current		
With 15.0 V filament voltage .....	375	a
With 15.5 V filament voltage .....	500	a
Control-Grid Dissipation .....	1000	W
Screen-Grid Dissipation .....	3000	W
Plate Dissipation .....	175	kW
Pulse Duration .....	500	$\mu$ s**
Duty Factor .....	.1	**

#### Typical Operation

Peak Plate Pulse Supply Voltage .....	30	kv
Peak Screen-Grid Pulse Supply Voltage .....	2750	v
DC Control-Grid Voltage .....	-2000	V
Peak RF Plate Voltage .....	26	kv
Peak RF Control-Grid Voltage .....	2750	v
Peak Plate Current from Pulse Supply .....	62	a
Peak Screen-Grid Current from Pulse Supply .....	7	a
Peak Rectified Control-Grid Current .....	2	a
RF Load Impedance .....	210	ohms
Driving Power during Pulse .....	5.1	kw
Power Output during Pulse .....	1.5	Mw
Duty Factor .....	.1	

§Modulation essentially negative may be used if the positive peak of the envelope does not exceed 115% of the carrier conditions.

‡Averaged over any audio-frequency cycle of sine-wave form.

\*All given maximum ratings may not apply simultaneously. Due to the possibility of instantaneous overheating of electrodes during the pulse, it may be necessary to restrict some of the parameters, e.g., peak plate current, tube drop, pulse duration, duty or average dissipation, in order not to adversely affect the performance of the tube. Because of the many possible combinations of operating conditions, all restrictions cannot be delineated here, and it is suggested to review new applications with the Machlett Engineering Department.

\*\*For application requiring longer pulse duration or higher duty factors, consult the Machlett Engineering Department.

### TUBE PROTECTION

The handling of very high power requires particular attention to the removal of power from tubes during fault conditions (initiated by tube or circuit instabilities) since the larger amount of energy involved can cause tube damage if not properly controlled. The tube must, therefore, be protected by limiting the time elapsed from inception of a fault condition to diverting the energy from the tube, as well as the amount of energy expended in the tube during this interval.

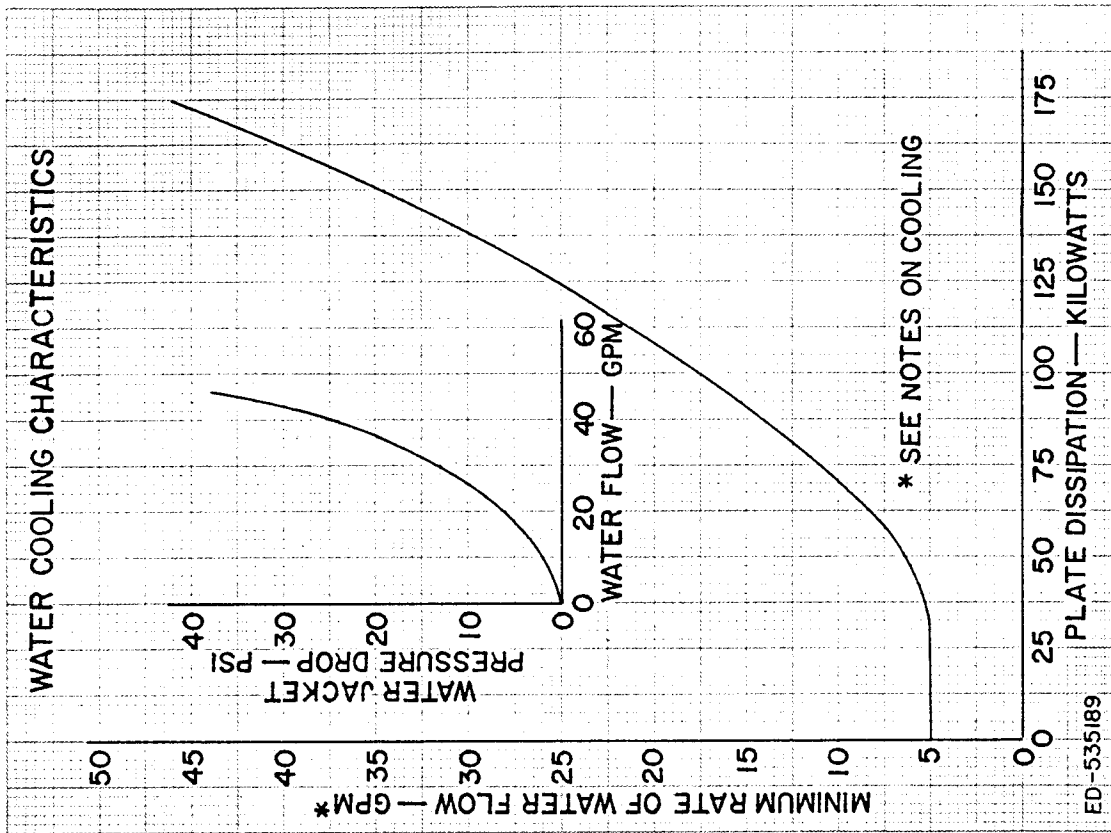
In addition to the normal circuit breakers and overload relays, it is necessary that a fast-acting electronic protective device (crowbar) or equivalent be used. This device will in most cases be a triggered gaseous device connected across the output of the plate supply filter, if used, to dissipate the filter-circuit energy as well as the rectifier output. The complete energy source must be shorted out as quickly as possible after the inception of a "fault", and in most cases the time interval should not be allowed to exceed approximately ten microseconds. For some basic electronic-crowbar fault-protection circuit considerations, as well as tests of the effectiveness of a protection device, refer to the references listed.

A nominal value of resistance must be placed in the plate lead of the tube being protected in order to be assured that the impedance of this tube under a flash arc condition is greater than that of the crowbar device when the latter is triggered. Critical damping is required for the crowbar discharge circuit. It is also recommended that a minimum of five to ten ohms resistance be connected in series with each rectifier tube in order to limit surge currents.

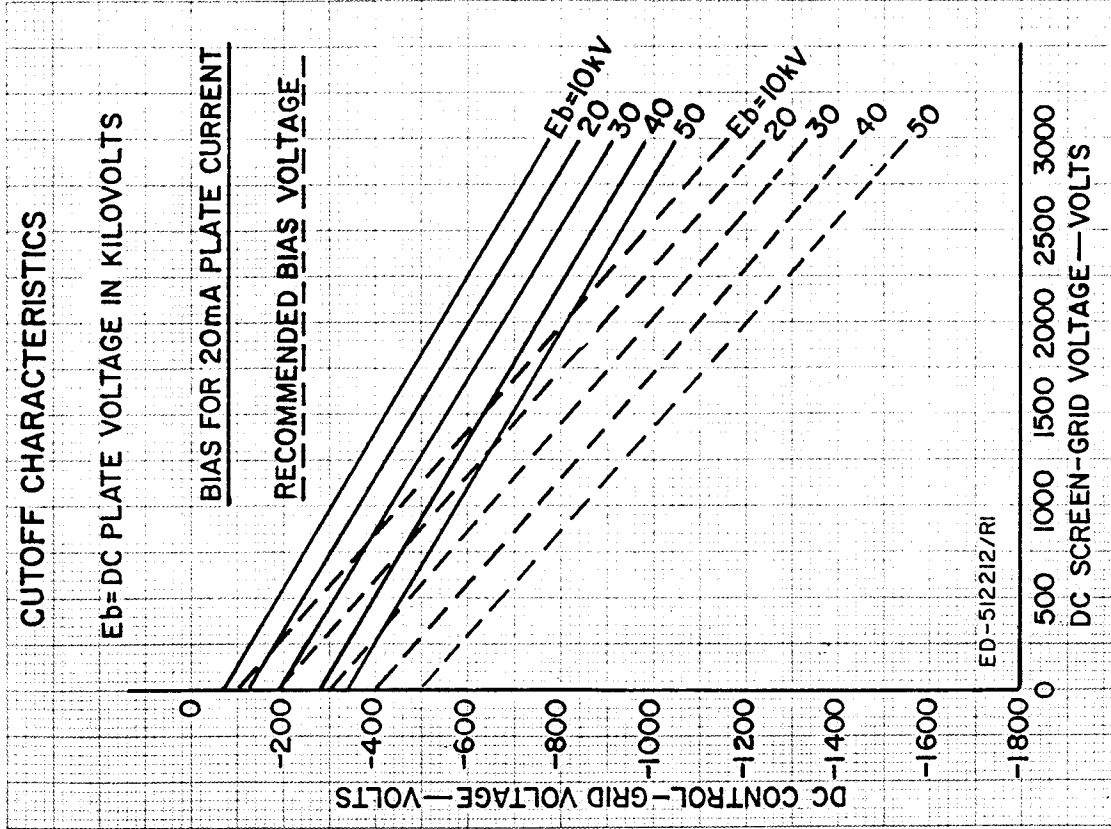
In circuits where high transient voltages may be developed due to a shorted load or other fault, special precautions are necessary to keep these excessive voltages from appearing at the tube electrodes.

#### References:

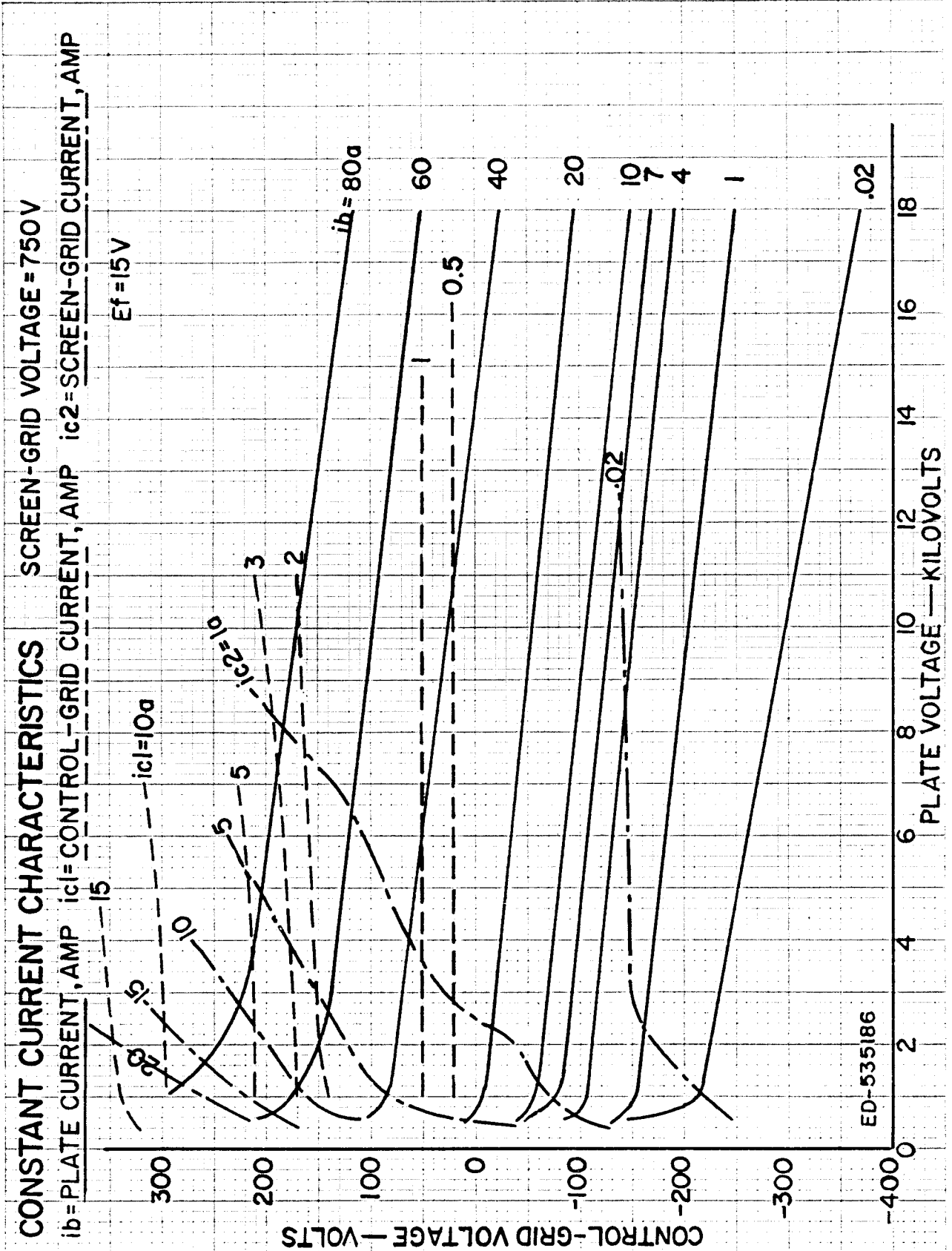
1. W. N. Parker and M. V. Hoover, "Gas Tubes Protect High Power Transmitters", *Electronics*, 29, 144, January 1956.
2. H. D. Doolittle, "High Power Hydrogen Thyratrons", *Cathode Press* 1, 6, 1954.

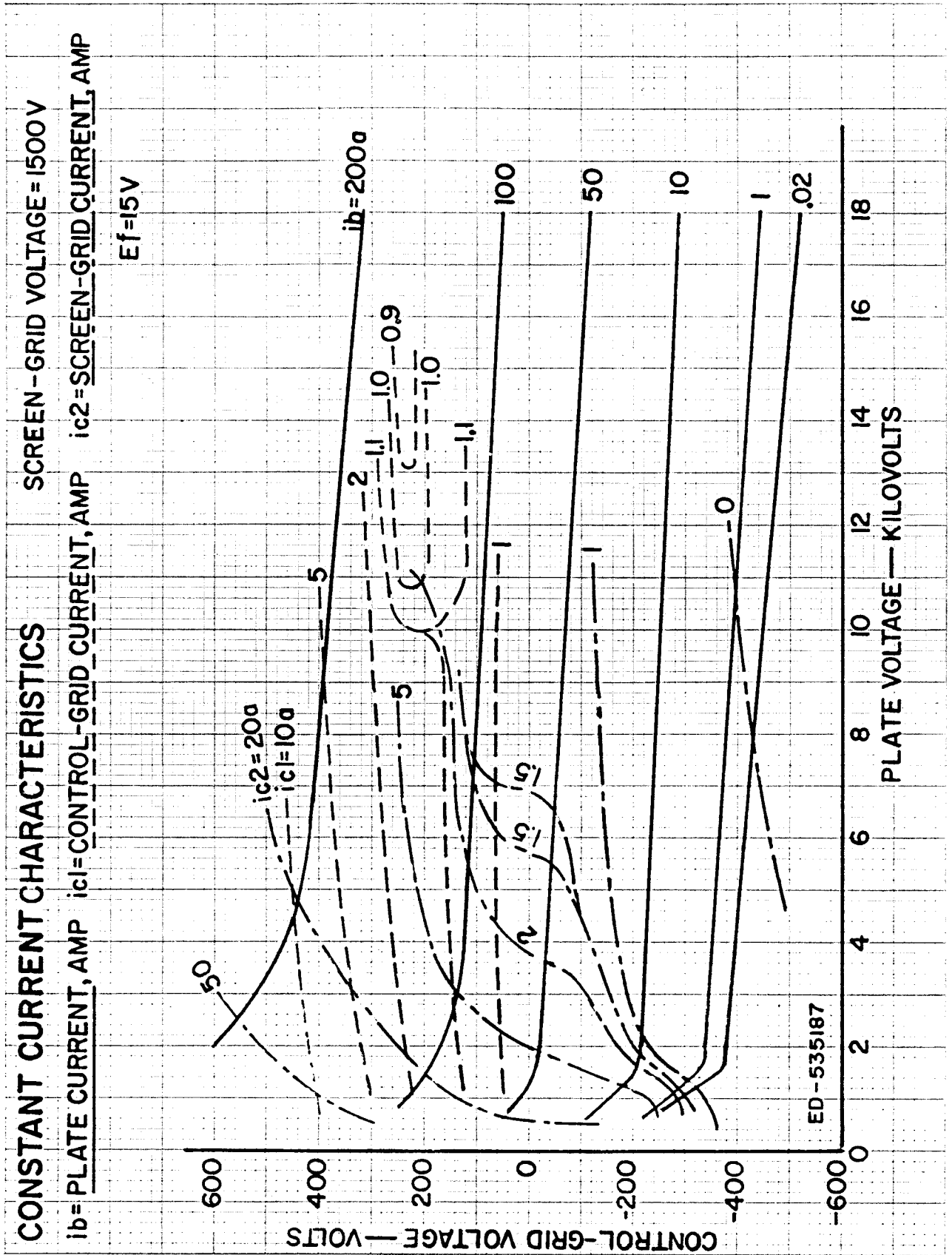


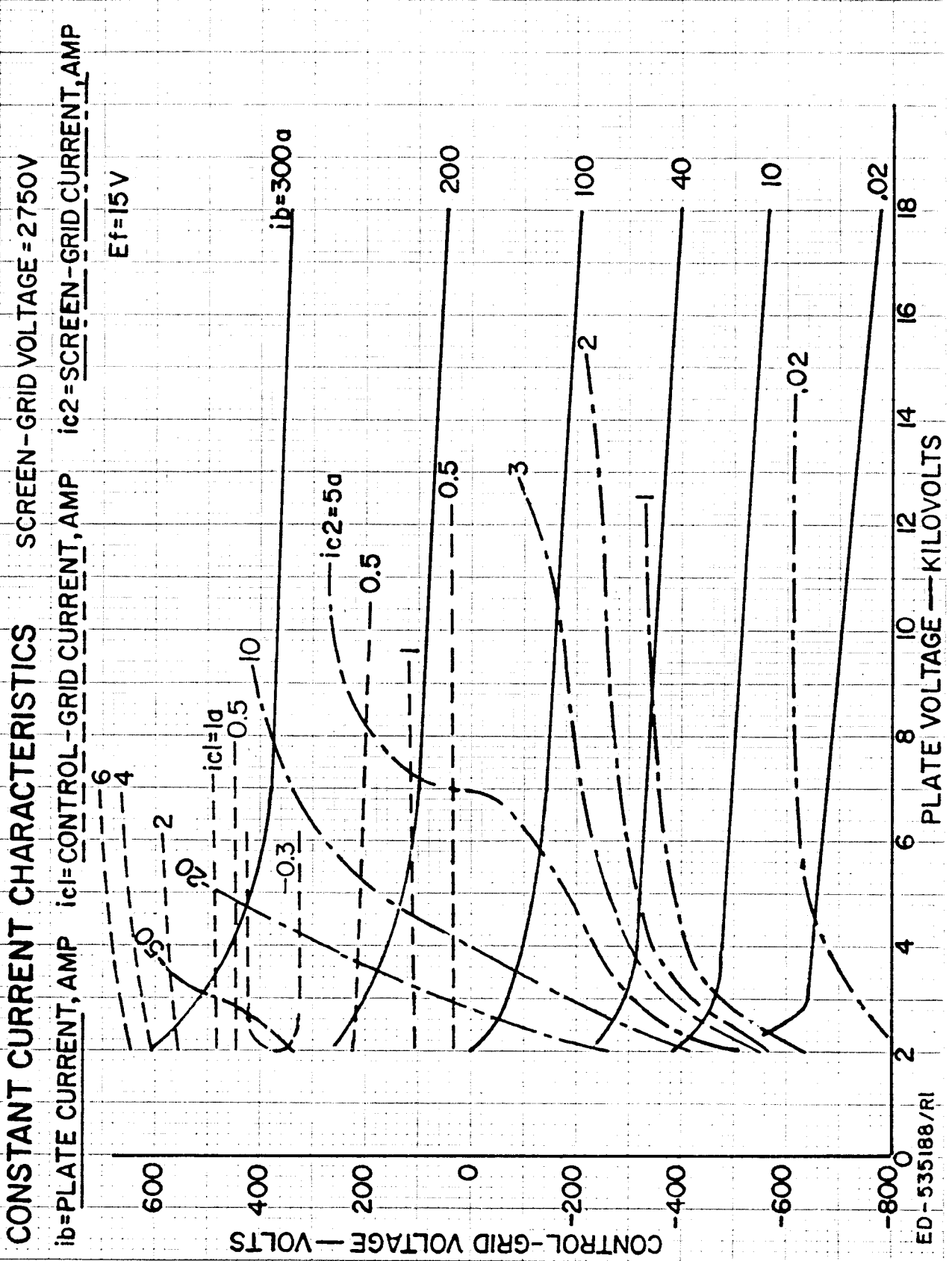
WATER COOLING CHARACTERISTICS  
 ML-8786

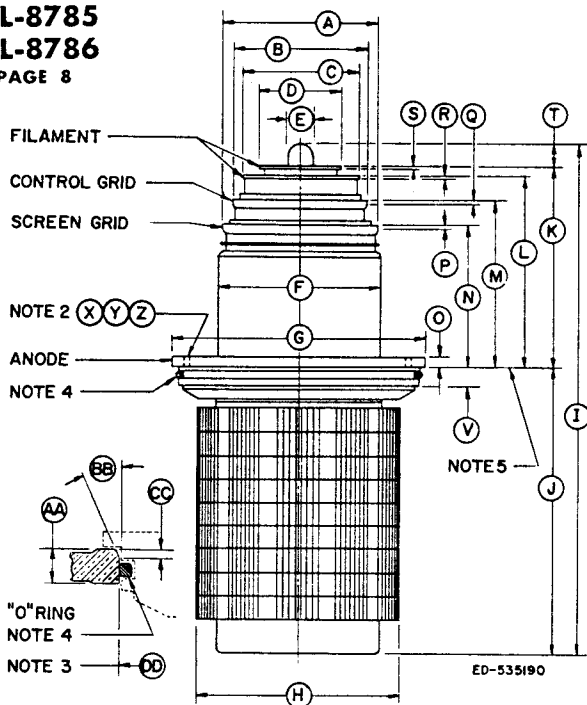


CUTOFF CHARACTERISTICS  
 ML-8785, ML-8786









DETAIL OF RECOMMENDED  
OPENING IN COOLING JACKET

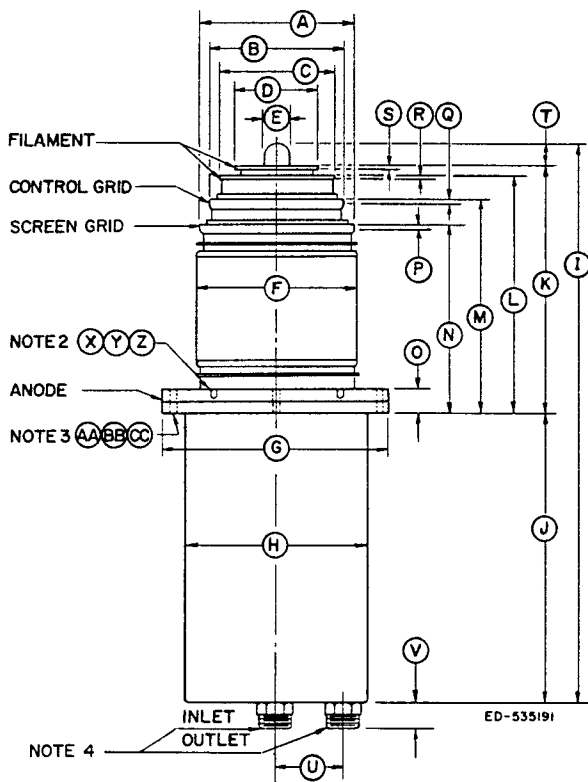
OUTLINE OF ML-8785

DIMENSIONS FOR OUTLINE OF ML-8785

Ref.	Inches			Notes
	Minimum	Nominal	Maximum	
A	6.87	6.94	6.97	1
B	5.87	5.94	5.97	1
C	5.17	5.19	5.21	1
D	3.60	3.62	3.64	1
E	—	1.12	1.19	
F	—	7.19	7.40	
G	11.26	11.31	11.35	
H	—	9.00	9.05	
I	—	—	23.07	
J	—	12.72	12.85	
K	8.40	8.78	9.09	
L	7.92	8.24	8.46	
M	7.06	7.24	7.42	
N	6.01	6.13	6.25	
O	.34	.37	.40	
P	.22	.25	—	
Q	.22	.25	—	
R	.23	.25	—	
S	.23	.25	—	
T	—	1.06	1.17	
V	.92	.94	.96	
X	.44	.50	—	2
Y	9.610	9.625	9.640	2
Z	3.680	3.686	3.692	2
AA	—	.75	—	
BB	—	20°	—	degrees
CC	—	.19	—	
DD	10.498	10.503	10.508	3

NOTES:

1. Includes out-of-roundness.
2. Eight 1/4"-20 topped holes, (X) deep, on circle diameter (Y), spaced at chordal distances (Z). For lifting tube.
3. Recommended diameter of opening for tube in cooling jacket.
4. O ring, Machlett Part No. P-25946, supplied with tube.
5. Tube to be supported in equipment only by this surface.



OUTLINE OF ML-8786

DIMENSIONS FOR OUTLINE OF ML-8786

Ref.	Inches			Notes
	Minimum	Nominal	Maximum	
A	6.87	6.94	6.97	1
B	5.87	5.94	5.97	1
C	5.17	5.19	5.21	1
D	3.60	3.62	3.64	1
E	—	1.12	1.19	
F	—	7.19	7.40	
G	9.94	10.00	10.06	
H	—	8.00	8.13	
I	—	—	25.17	
J	12.56	12.81	13.06	
K	10.53	10.84	11.15	
L	10.09	10.30	10.51	
M	9.12	9.30	9.48	
N	8.07	8.19	8.31	
O	1.06	1.12	1.18	
P	.22	.25	—	
Q	.22	.25	—	
R	.23	.25	—	
S	.23	.25	—	
T	—	1.06	1.17	
U	2.81	3.00	3.19	
V	—	1.12	1.50	
X	.33	.39	—	2
Y	8.16	8.19	8.22	2
Z	5.77	5.79	5.81	2
AA	9.13	9.16	9.19	3
BB	6.46	6.48	6.50	3
CC	.286	.290	.298	3

NOTES:

1. Includes out-of-roundness.
2. Four 1/4"-20 topped holes, (X) deep, on circle diameter (Y), spaced at chordal distances (Z). For lifting tube.
3. Four thru holes, diameter (CC), on circle diameter (AA), spaced at chordal distances (BB). For mounting and plate-circuit connections.
4. Water-cooling connections, one-inch pipe thread (NPT).



THE MACHLETT LABORATORIES, INC.

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